CEN School of Integrated Climate and Earth System Sciences (SICSS)
Membership Application Guidelines (Doctoral Program)

General information / Prerequisites
The graduate school SICSS is part of the Centre of Earth System Sciences and Sustainability (CEN) at Universität Hamburg.

SICSS links doctoral candidates of different scientific background and expertise and enables an integrated, innovative education in climate system sciences. SICSS offers compulsory elements such as the introduction course and the annual retreat as well as elective courses on research or soft skills. SICSS also provides counseling on career development and planning. Core element of SICSS is the advisory panel system, a mentoring and guidance tool.

SICSS is open to all doctoral candidates at Universität Hamburg. The doctoral program in SICSS addresses research-oriented students with very good MSc degrees in earth system sciences and complementary disciplines dealing with climate research. Either the advisor or co-advisor of the doctoral candidate has to be involved in CEN.

Application procedure
Membership applications are possible at any given time. New members are usually welcomed twice a year, at the beginning of the semester in April and October. A membership is granted for three years starting with the date of official admission as doctoral candidate at Universität Hamburg (‘Zulassung zur Promotion’).

SICSS evaluates the application based on the following documents to be submitted by the candidate:
1. a motivation letter that demonstrates the interests in becoming a SICSS member,
2. a curriculum vitae,
3. the MSc certificate (or equivalent) and transcript of records (copies only!),
4. a thesis outline, summarizing the topic and the focus of the doctoral project.

The membership becomes finally valid once the candidate has handed in the following documents:
1. copy of the admission as doctoral candidate at Universität Hamburg (‘Zulassung zur Promotion’),
2. information on the funding source and the duration of the funding,
3. supervision agreement signed by the advisor, co-advisor, panel chair and candidate (template).

Note: All documents may be send as copies in electronic form (pdf). Do not send original documents by post!

Questions or applications via e-mail to: ingo.harms@uni-hamburg.de
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